N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY			
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)	Q_g (Typ.)
30	0.093 at V_{GS} = 10 V	1.3[a]	5.41
	0.129 at V_{GS} = 4.5 V	1.2	

FEATURES

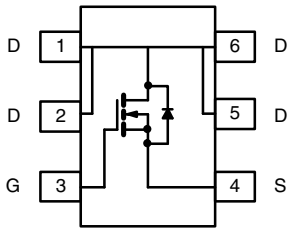
- **Halogen-free According to IEC 61249-2-21 Definition**
- TrenchFET® Power MOSFET
- 100 % R_g and UIS Tested
- Compliant to RoHS Directive 2002/95/EC

Pb-free
RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

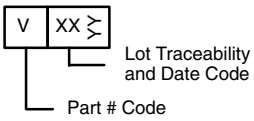
- Load Switch for Portable Devices

SC-89 (6-LEADS)



Top View

Marking Code



Ordering Information: Si1072X-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)				
Parameter		**Symbol**	**Limit**	**Unit**
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current (T_J = 150 °C)[a]	T_A = 25 °C	I_D	1.3[b, c]	A
	T_A = 70 °C		1.03[b, c]	
Pulsed Drain Current		I_{DM}	6	
Avalanche Current	L = 0.1 mH	I_{AS}	8	
Repetitive Avalanche Energy		E_{AS}	3.2	mJ
Continuous Source-Drain Diode Current	T_A = 25 °C	I_S	0.2[b, c]	A
Maximum Power Dissipation[a]	T_A = 25 °C	P_D	0.236[b, c]	W
	T_A = 70 °C		0.151[b, c]	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		**Symbol**	**Typical**	**Maximum**	**Unit**
Maximum Junction-to-Ambient[b, d]	t ≤ 5 s	R_{thJA}	440	530	°C/W
	Steady State		540	650	

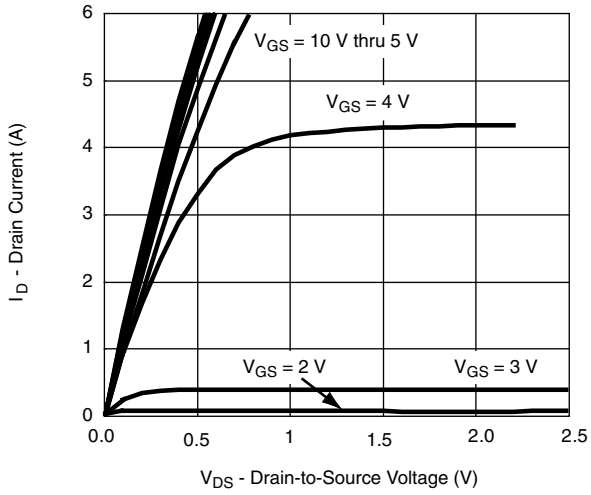
Notes:
a. Based on T_C = 25 °C.
b. Surface mounted on 1" x 1" FR4 board.
c. t = 5 s.
d. Maximum under steady state conditions is 650 °C/W.

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
Parameter	**Symbol**	**Test Conditions**	**Min.**	**Typ.**	**Max.**	**Unit**
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	30			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	I_D = 250 µA		30.4		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 1.86		
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1		3	V
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V			1	µA
		V_{DS} = 30 V, V_{GS} = 0 V, T_J = 85 °C			10	
On-State Drain Current[a]	$I_{D(on)}$	V_{DS} = ≥ 5 V, V_{GS} = 10 V	6			A
Drain-Source On-State Resistance[a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 1.3 A		0.077	0.093	Ω
		V_{GS} = 4.5 V, I_D = 1.2 A		0.107	0.129	
Forward Transconductance	g_{fs}	V_{DS} = 15 V, I_D = 1.3 A		15		mS
Dynamic[b]						
Input Capacitance	C_{iss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		280		pF
Output Capacitance	C_{oss}			55		
Reverse Transfer Capacitance	C_{rss}			35		
Total Gate Charge	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D = 1.3 A		5.5	8.3	nC
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 1.3 A		2.7	4.1	
Gate-Source Charge	Q_{gs}			1.1		
Gate-Drain Charge	Q_{gd}			0.8		
Gate Resistance	R_g	f = 1 MHz		3.5	4.6	Ω
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 15 V, R_L = 13.6 Ω I_D ≅ 1.1 A, V_{GEN} = 10 V, R_g = 1 Ω		7	11	ns
Rise Time	t_r			12	18	
Turn-Off DelayTime	$t_{d(off)}$			12	18	
Fall Time	t_f			6	9	
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 15 V, R_L = 15.5 Ω I_D ≅ 0.97 A, V_{GEN} = 10 V, R_g = 1 Ω		13	20	
Rise Time	t_r			31	47	
Turn-Off DelayTime	$t_{d(off)}$			9	14	
Fall Time	t_f			6	9	
Drain-Source Body Diode Characteristics						
Pulse Diode Forward Current[a]	I_{SM}				6	A
Body Diode Voltage	V_{SD}	I_S = 0.7 A		0.8	1.2	V
Body Diode Reverse Recovery Time	t_{rr}	I_F = 1.2 A, dI/dt = 100 A/µs		11.2	17	nC
Body Diode Reverse Recovery Charge	Q_{rr}			4.5	6.8	ns
Reverse Recovery Fall Time	t_a			7.5		
Reverse Recovery Rise Time	t_b			3.7		

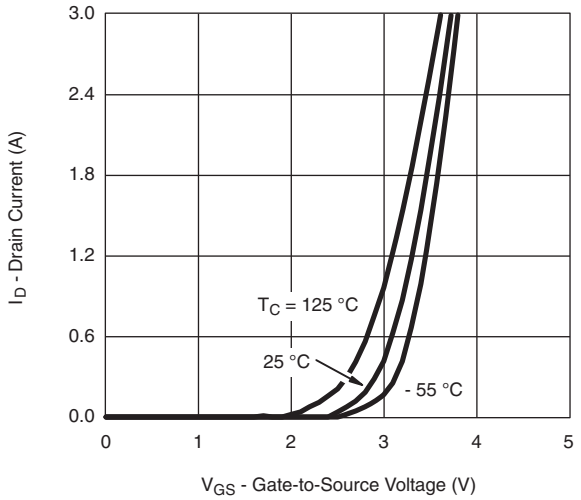
Notes:
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

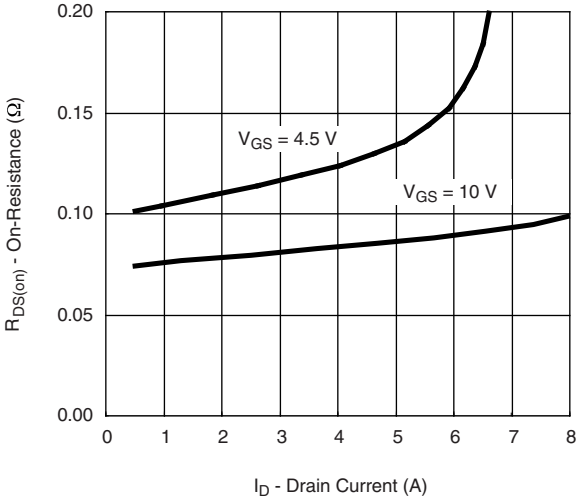
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



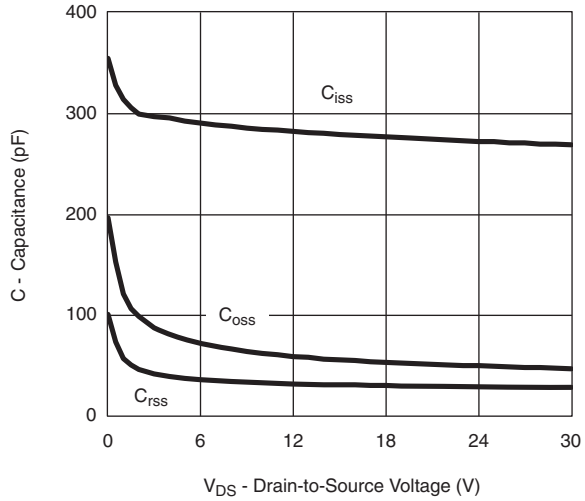
Output Characteristics



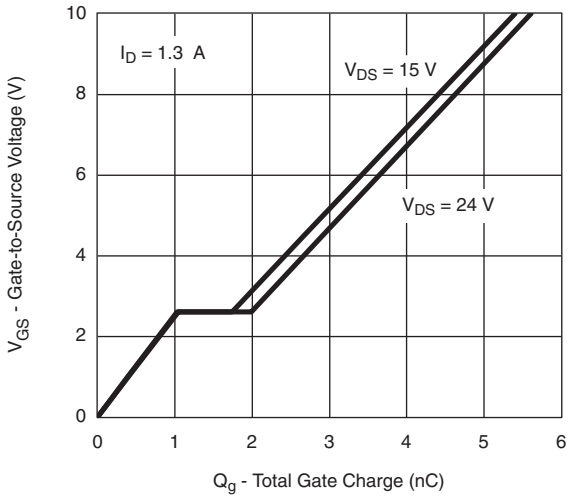
Transfer Characteristics Curves vs. Temp.



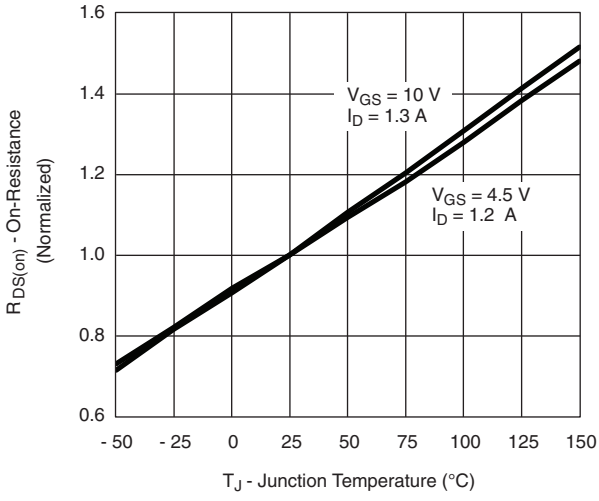
On-Resistance vs. Drain Current



Capacitance

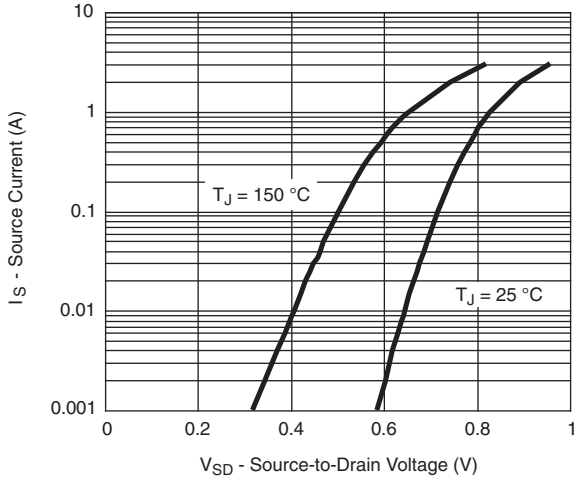


Gate Charge

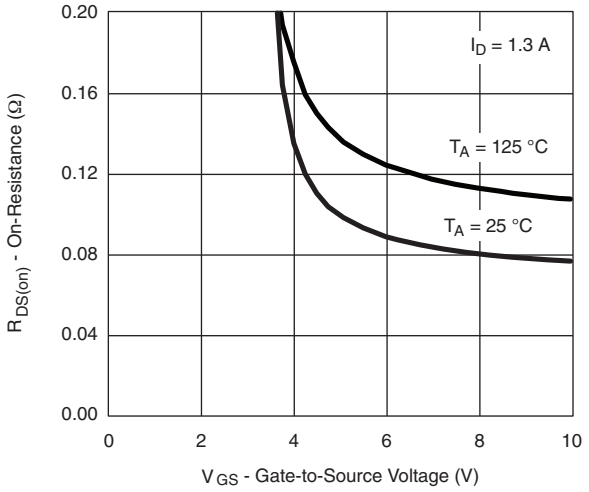


On-Resistance vs. Junction Temperature

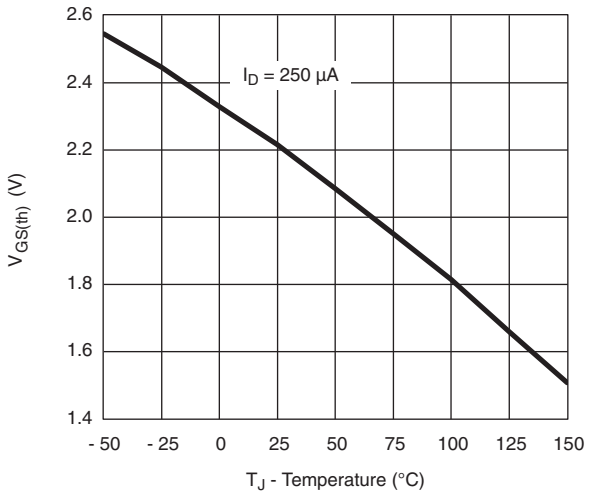
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



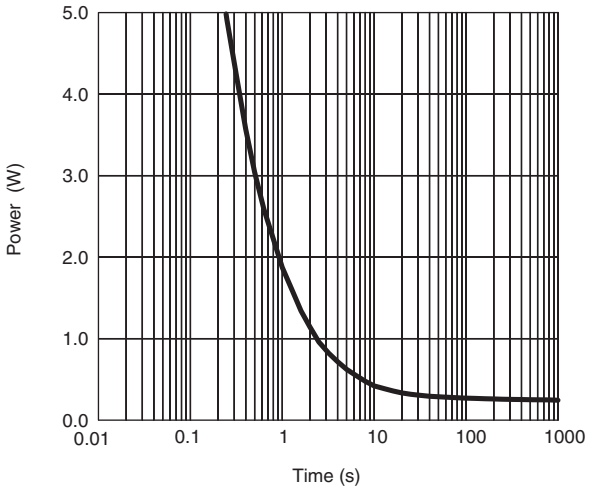
Source-Drain Diode Forward Voltage



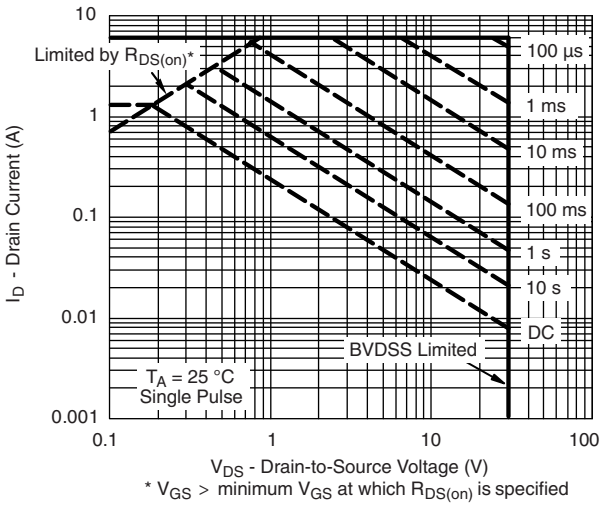
$R_{DS(on)}$ vs. V_{GS} vs. Temperature



Threshold Voltage

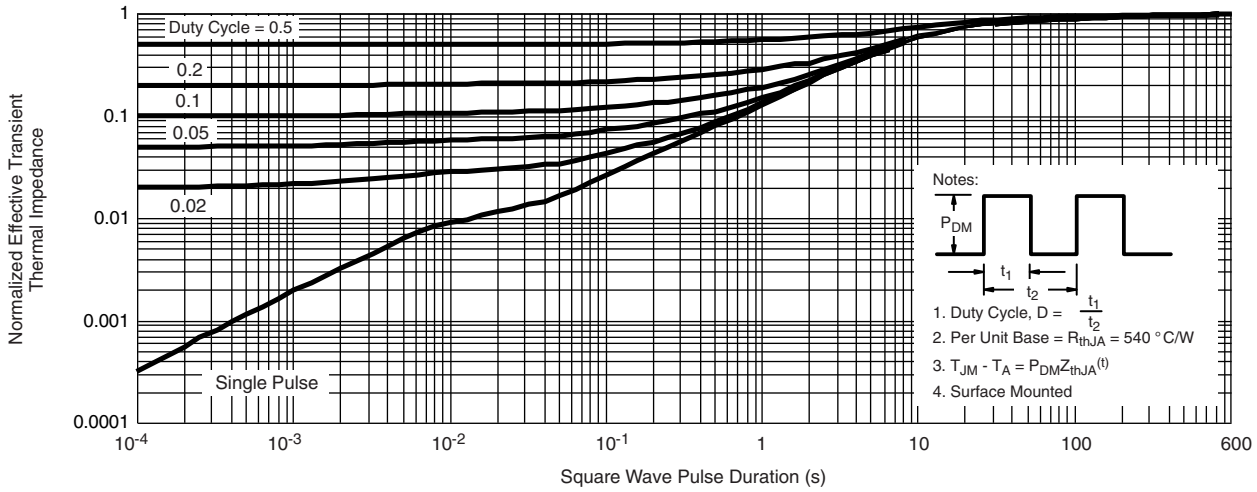


Single Pulse Power



Safe Operating Area, Junction-to-Ambient

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

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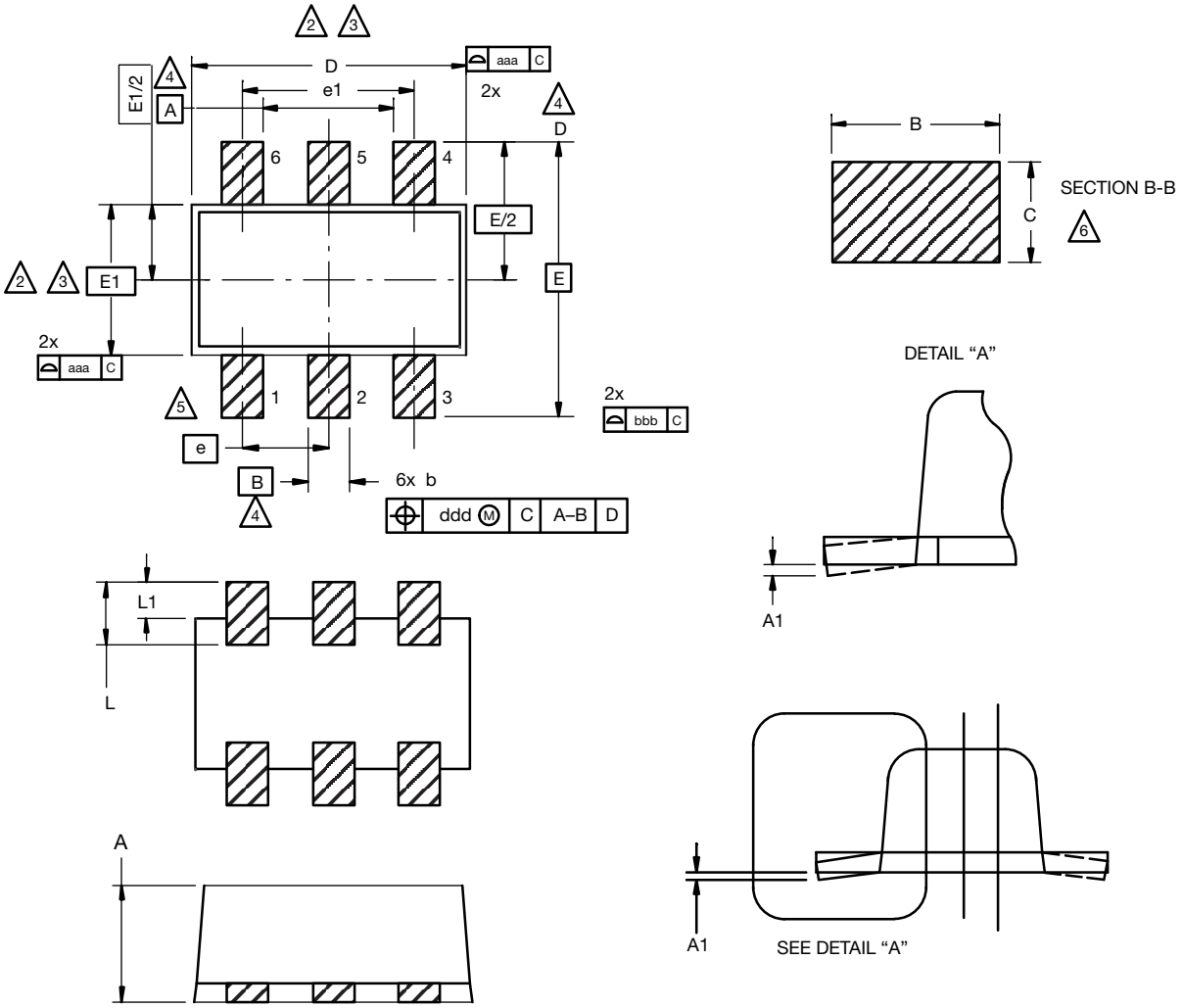
SC-89 6-Leads (SOT-563F)



Notes

1. Dimensions in millimeters.

2. Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.

3. Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

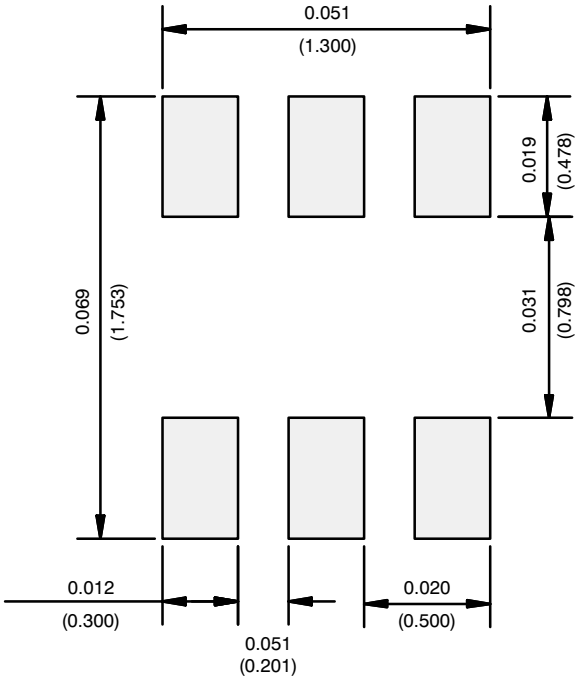
4. Datums A, B and D to be determined 0.10 mm from the lead tip.

5. Terminal numbers are shown for reference only.

6. These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIM.	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.56	0.58	0.60
A1	0	0.02	0.10
b	0.15	0.22	0.30
c	0.10	0.14	0.18
D	1.50	1.60	1.70
E	1.50	1.60	1.70
E1	1.15	1.20	1.25
e	0.45	0.50	0.55
e1	0.95	1.00	1.05
L	0.25	0.35	0.50
L1	0.10	0.20	0.30
C14-0439-Rev. C, 11-Aug-14 DWG: 5880			

RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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